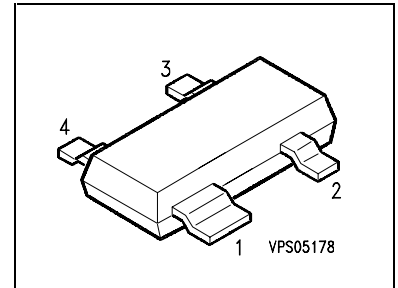


Silicon Bipolar MMIC-Amplifier

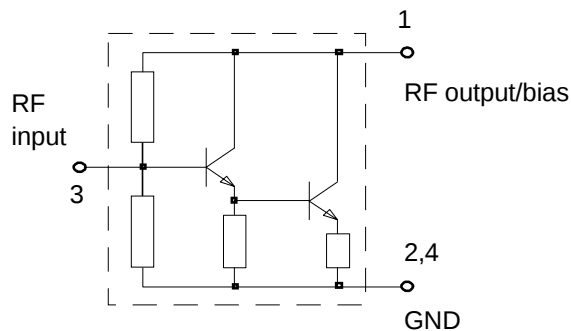
Preliminary Data

- Cascadable 50 Ω -Gain Block
- 16 dB typical Gain at 1.0 GHz
- 12 dBm typical P_{-1dB} at 1.0 GHz
- 3 dB-Bandwidth: DC to 1.2 GHz
- Plastic Package



Type	Marking	Ordering Code (8-mm taped)	Pin Configuration (circuit Diagram)	Package ¹⁾
BGA318	BNs	Q62702-G0043	see below	SOT143

Circuit Diagram



Maximum Ratings

Parameter	Symbol		Unit
Device current	I_D	60	mA
Total power dissipation, $T_s \leq 99^\circ\text{C}$ ²⁾	P_{tot}	250	mW
RF input power	P_{RFin}	5	dBm
Junction temperature	T_j	150	$^\circ\text{C}$
Ambient temperature range	T_A	-65...+150	$^\circ\text{C}$
Storage temperature range	T_{stg}	-65...+150	$^\circ\text{C}$

Thermal Resistance

Junction-soldering point ²⁾	$R_{th JS}$	≤ 205	K/W
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1)For detailed information see page 4

2) T_S is measured on the RFoutput lead at the soldering point to the pcb.

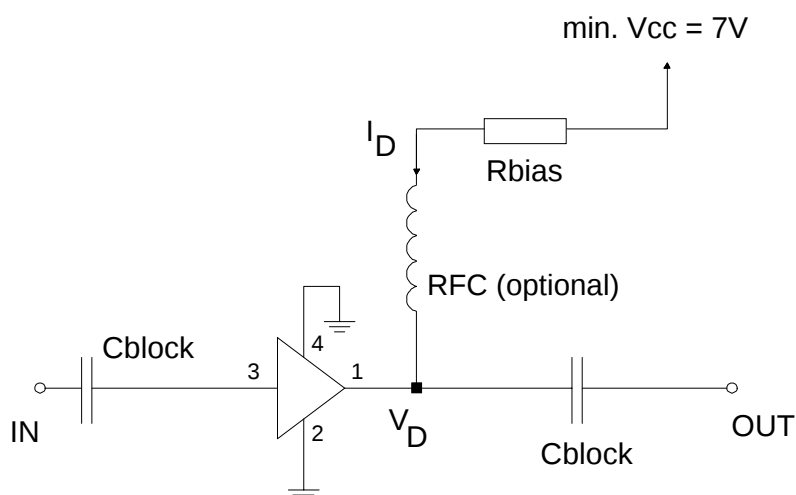
Electrical Characteristics

at $T_A = 25^\circ\text{C}$, unless otherwise specified.

$V_D = 4.7\text{ V}$, $Z_0 = 50\ \Omega$

Parameter	Symbol	Value			Unit
		min.	typ.	max.	
Insertion power gain $f = 0.1\text{ GHz}$ $f = 1.0\text{ GHz}$ $f = 1.8\text{ GHz}$	$ S_{21} ^2$		18 16 12		dB
Insertion power gain flatness $f = 0.1\text{ GHz to }0.6\text{ GHz}$	$\Delta S_{21} ^2$		± 0.7		dB
Noise figure $f = 0.1\text{ GHz}$ $f = 1.0\text{ GHz}$ $f = 2\text{ GHz}$	NF		3.5 4.0 5.0		dB
1dB Compression point output $f = 1\text{ GHz}$	$P_{-1\text{dB}}$		12		dBm
Return Loss $f = 0.1\text{ GHz to }2\text{ GHz}$ Input $f = 0.1\text{ GHz to }3\text{ GHz}$ Output	RL_{in} RL_{out}		14 10		dB

Typical Biasing Configuration



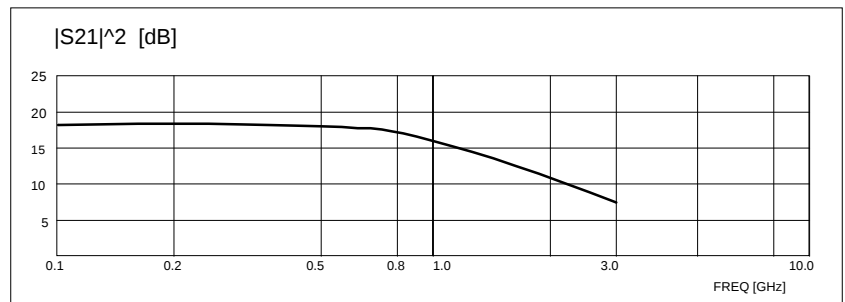
$$R_{bias} = \frac{V_{CC} - V_D}{I_D}$$

$$V_D = 4.7\text{ V}$$

Insertion power gain

vs. frequency

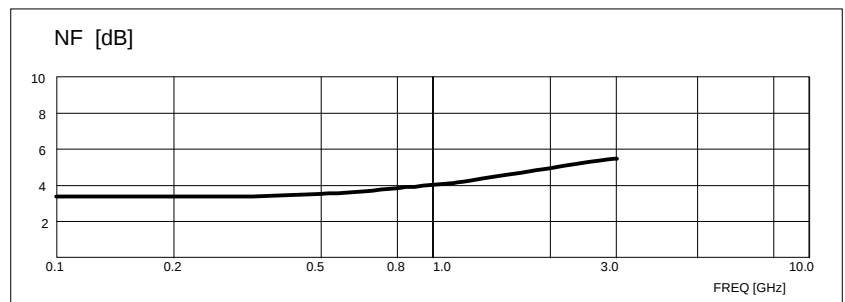
$V_D = 4.7 \text{ V}$, $I_D = 35 \text{ mA}$



Noise figure

vs. frequency

$V_D = 4.7 \text{ V}$, $I_D = 35 \text{ mA}$

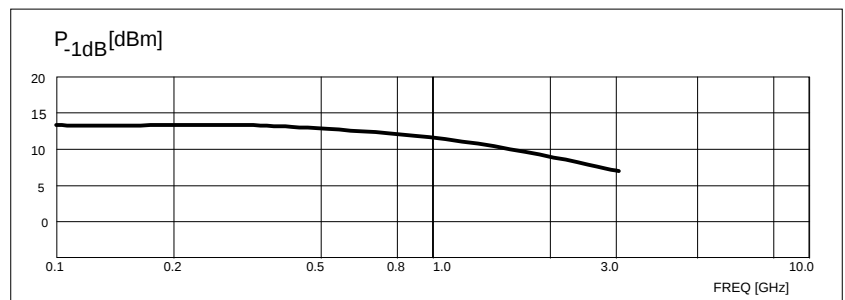


Output power

1-dB-Gain compression

vs. frequency

$V_D = 4.7 \text{ V}$, $I_D = 35 \text{ mA}$



Typical S-Parameters at

$T_A = 25 \text{ °C}$

f	S_{11}		S_{21}		S_{12}		S_{22}	
GHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
$V_D = 4.7 \text{ V}$, $Z_0 = 50 \text{ } \Omega$								
0.010	0.196	0.2	8.01	178.9	0.077	0.6	0.327	-0.5
0.100	0.193	-4.8	8.00	171.6	0.078	4.9	0.324	-8.6
0.300	0.194	-14.4	7.75	155.4	0.082	13.8	0.312	-25.0
0.500	0.191	-25.9	7.28	139.9	0.089	21.1	0.294	-41.2
0.800	0.184	-45.0	6.43	119.1	0.105	27.9	0.260	-62.9
1.000	0.175	-60.3	5.83	106.8	0.117	30.2	0.238	-76.2
1.800	0.185	-130.6	3.91	67.6	0.164	30.2	0.184	-113.0
2.400	0.241	-170.6	2.99	45.5	0.193	26.8	0.173	-124.4
3.000	0.298	159.6	2.38	27.6	0.218	22.8	0.178	-131.2